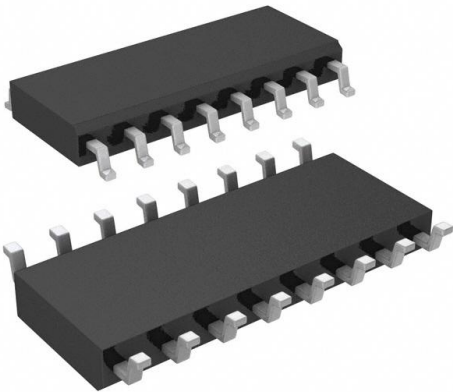


DG509ADY+T Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DG509ADY+T-DG
Manufacturer	Analog Devices Inc./Maxim Integrated
Manufacturer Product Number	DG509ADY+T
Description	IC SWITCH SP4T X 2 450OHM 16SOIC
Detailed Description	2 Circuit IC Switch 4:1 450Ohm 16-SOIC



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

DG509ADY+T

Series:

-

Switch Circuit:

SP4T

Number of Circuits:

2

Channel-to-Channel Matching (ΔR_{on}):

270 Ω

Voltage - Supply, Dual (V_{\pm}):

$\pm 4.5V \sim 18V$

-3db Bandwidth:

-

Channel Capacitance ($C_{S(off)}$, $C_{D(off)}$):

5pF, 12pF

Crosstalk:

-

Mounting Type:

Surface Mount

Supplier Device Package:

16-SOIC

Manufacturer:

Analog Devices Inc./Maxim Integrated

Product Status:

Active

Multiplexer/Demultiplexer Circuit:

4:1

On-State Resistance (Max):

4500 Ω

Voltage - Supply, Single (V_{+}):

-

Switch Time (T_{on} , T_{off}) (Max):

1.5 μs , 1 μs

Charge Injection:

-

Current - Leakage ($I_{S(off)}$) (Max):

1nA

Operating Temperature:

-40 $^{\circ}C \sim 85^{\circ}C$ (TA)

Package / Case:

16-SOIC (0.154", 3.90mm Width)

Base Product Number:

DG509

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8542.39.0001

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

DG508A/DG509A

Monolithic CMOS Analog Multiplexers

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-

V+	+44V
GND	+25V
Digital Inputs, V _S and V _D (Note 1)	-2V to (V+ + 2V)
	or 20mA, whichever occurs first

Current (any terminal, except S or D)

Continuous Current, S or D

Peak Current, S or D (pulsed at 1ms, 10% duty cycle max) ..

Continuous Power Dissipation (T_A = +70°C)

Plastic DIP (derate 10.53mW/°C above +70°C)

Narrow SO (derate 8.70mW/°C above +70°C)

Wide SO (derate 9.52mW/°C above +70°C)

CERDIP (derate 10.00mW/°C above +70°C)

Operating Temperature Ranges:

DG50_ACJ/CWE

DG50_ABK

DG50_ADJ/DY/EWE

DG50_AAK/MY

Storage Temperature Range

Lead Temperature (soldering, 10s)

Soldering Temperature (reflow)

PDIP, Wide SO, Narrow SO, CERDIP containing lead(Pb) ..

PDIP, Wide SO, Narrow SO lead(Pb)-free

Note 1: Signals on S₋ or D₋ exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V+ = 15V, V- = -15V, V_{GND} = 0V, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	DG508AA/M DG509AA/M			DG508AD/E/B/C DG509AD/E/B/C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
SWITCH									
Analog Signal	V _{ANALOG}		-15		+15	-15		+15	V
Drain-Source On-Resistance	R _{DS(ON)}	Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V (Note 4)	V _D = 10V, I _S = -200μA		170	400	170	450	Ω
			V _D = -10V, I _S = 200μA		130	400	130	450	
Greatest Change in Drain-Source On-Resistance Between Channels	ΔR _{DS(ON)}	$\Delta R_{DS(ON)} = \left(\frac{R_{DS(ON) \max} - R_{DS(ON) \min}}{R_{DS(ON)}} \right)$			6		6		%
Source Off-Leakage Current	I _{S(OFF)}	V _{EN} = 0V	V _S = 10V, V _D = -10V		0.002	0.5	0.002	1	nA
			V _S = -10V, V _D = 10V		-0.5	-0.005	-1	-0.005	
Drain Off-Leakage Current	DG508A	V _{EN} = 0V	V _D = 10V, V _S = -10V		0.01	2	0.01	5	nA
			V _D = -10V, V _S = 10V		-2	-0.015	-5	-0.015	
	DG509A		V _D = 10V, V _S = -10V		0.005	2	0.005	5	
			V _D = -10V, V _S = 10V		-2	-0.008	-5	-0.008	
Drain On-Leakage Current	DG508A	Sequence each switch on, V _{A_L} = 0.8V V _{A_H} = 2.4V (Note 2)	V _{S(all)} = V _D = 10V		0.015	2	0.015	5	nA
			V _{S(all)} = V _D = -10V		-2	-0.03	-5	-0.03	
	DG509A		V _{S(all)} = V _D = 10V		0.007	2	0.007	5	
			V _{S(all)} = V _D = -10V		-2	-0.015	-5	-0.015	

Monolithic CMOS Analog Multiplexers

ELECTRICAL CHARACTERISTICS (continued)

(V+ = 15V, V- = -15V, V_{GND} = 0V, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	DG508AA/M DG509AA/M			DG508AD/E/B/C DG509AD/E/B/C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
LOGIC INPUT									
Logic Input Current, Input Voltage High	I _{AH}	V _{A-} = 2.4V	-10	-		10	-0.002		μA
		V _{A-} = 15V		0.006	10		0.006	10	
Logic Input Current, Input Voltage Low	I _{AL}	All V _{A-} = 0V	V _{EN} = 2.4V	-10	-		10	-0.002	μA
			V _{EN} = 0V	-10	-		-10	-0.002	
DYNAMIC									
Multiplexer Switching	t _{transition}	Figure 1		0.6	1.0		0.6	1.0	μs
Break-Before-Make Interval	t _{OPEN}	Figure 3		0.2			0.2		μs
Enable Turn-On Time	t _{ON(EN)}	Figure 2		0.4	1.0		0.4	1.5	μs
Enable Turn-Off Time	t _{OFF(EN)}	Figure 2		0.2	0.7		0.2	1.0	μs
Off-Isolation	OIRR	V _{EN} = 0V, R _L = 1kΩ, C _L = 15pF, V _S = 7V _{RMS} f = 500kHz (Note 3)		68			68		dB
Source Off-Capacitance	C _{S(OFF)}	V _S = 0V, V _{EN} = 0V, f = 140kHz		5			5		pF
Drain Off- Capacitance	IDG508A	V _S = 0V, V _{EN} = 0V, f = 140kHz		25			25		pF
	DGS09A			12			12		
SUPPLY									
Positive Supply Current	I+	V _{EN} = 2.4V, all V _{A-} = 0V or 2.4V		0.02	0.2		0.02	0.2	mA
Negative Supply Current	I-	V _{EN} = 2.4V, all V _{A-} = 0V or 2.4V	-0.1	-0.01		-0.1	-0.01		mA
Positive Supply Current in Standby	I+	V _{EN} = 0V, all V _{A-} = 0V or 2.4V		0.02	0.2		0.02	0.2	mA
Negative Supply Current in Standby	I-	V _{EN} = 0V, all V _{A-} = 0V or 2.4V	-0.1	-0.01		-0.1	-0.01		mA
Power-Supply Range for Continuous Operation	V-, V+	(Notes 4, 5)	±4.5		±18.0	±4.5		±18.0	V

DG508A/DG509A

Monolithic CMOS Analog Multiplexers

DG508A/DG509A

ELECTRICAL CHARACTERISTICS

(V₊ = 15V, V_{GND} = 0V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	DG508AA/M DG509AA/M			DG508AD/E/B/C DG509AD/E/B/C			UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX		
SWITCH										
Analog Signal Range	V _{ANALOG}			-15	+15		-15	+15	V	
Drain-Source On-Resistance	R _{DS(ON)}	Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V	V _D = 10V, I _S = -200μA		500			550	Ω	
			V _D = -10V, I _S = 200μA		500			550		
Source Off-Leakage Current	I _{S(OFF)}	V _{EN} = 0V	V _S = 10V, V _D = -10V				+50		nA	
			V _S = -10V, V _D = -10V			-50		-50		
Drain Off-Leakage Current	DG508A DG509A	I _{D(OFF)}	V _{EN} = 0V	V _D = 10V, V _S = -10V			+200		nA	
				V _D = -10V, V _S = -10V	-200			-200		
				V _D = 10V, V _S = -10V			+200			+100
				V _D = -10V, V _S = -10V	-100			-100		
Drain On-Leakage Current	DG508A DG509A	I _{D(ON)}	Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V (Note 2)	V _{S(all)} = V _D = 10V			+200		nA	
				V _{S(all)} = V _D = -10V	-200			-100		
				V _{S(all)} = V _D = 10V			+100			+100
				V _{S(all)} = V _D = -10V	-100			-100		
LOGIC INPUT										
Logic Input Current, Input Voltage High	I _{AH}	V _{A_} = 2.4V		-30			-30		μA	
		V _{A_} = 15V				+30		+30		
Logic Input Current, Input Voltage Low	I _{AL}	All V _{A_} = 0V		V _{EN} = 2.4V	-30		-30		μA	
				V _{EN} = 0V	-30		-30			

Note 2: I_{D(ON)} is leakage from driver into on switch.

Note 3: Off-isolation = 20log $\frac{|V_S|}{|V_D|}$

V_S = input to off switch,
V_D = output due to V_S.

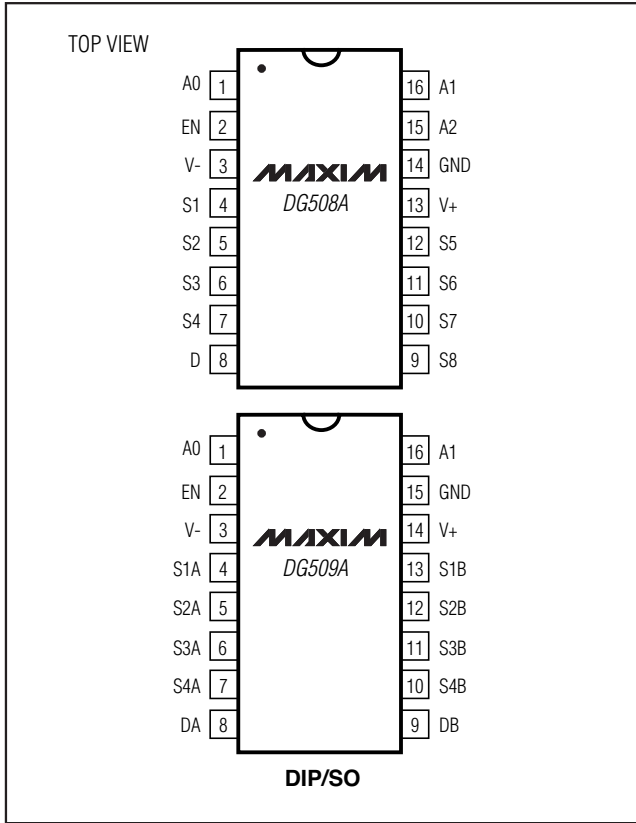
Note 4: Electrical characteristics (such as on-resistance) change when power supplies other than ±15V are used.

Note 5: For designs requiring single 5V or dual ±5V operation, refer to Maxim's improved MAX338 and MAX339. Minimum operating voltage for DG508ADY/MY and DG509ADY/MY is ±9V.

Monolithic CMOS Analog Multiplexers

DG508A/DG509A

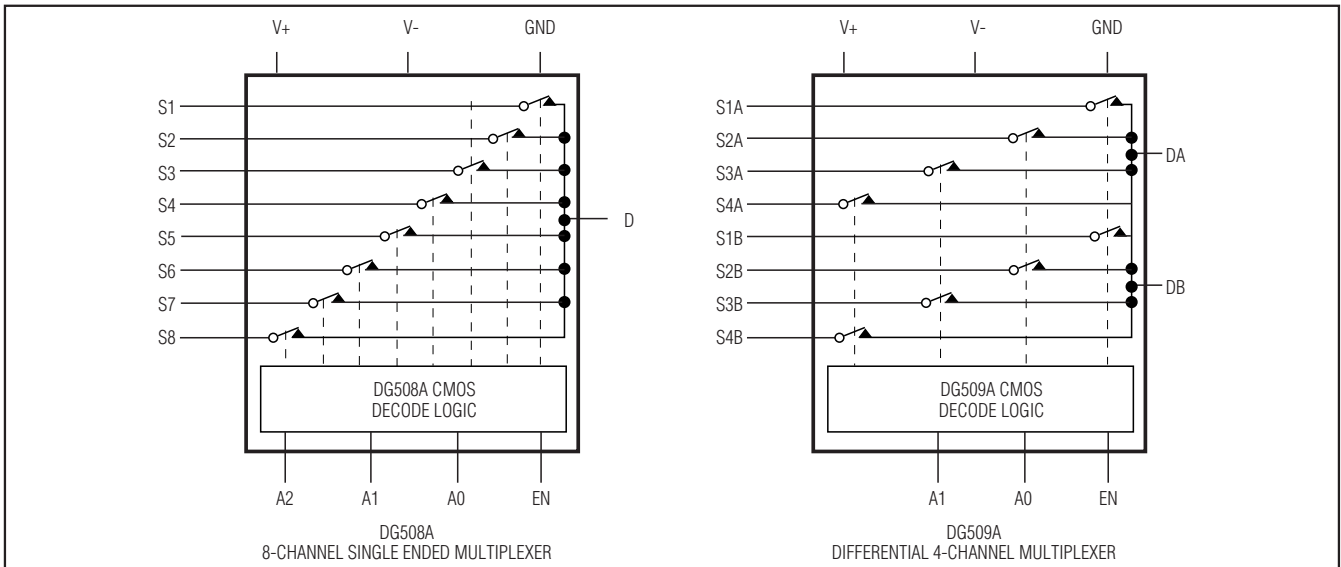
Pin Configurations



Pin Descriptions

PIN		NAME	FUNCTION
DG508A DIP/SO	DG509A DIP/SO		
1, 15, 16	—	A0, A2, A1	Address Input
—	1, 16	A0, A1	Address Input
2	2	EN	Enable
3	3	V-	Negative-Supply Voltage Input
4-7	—	S1-S4	Analog Inputs, Bidirectional
—	4-7	S1A-S4A	Analog Inputs, Bidirectional
8	—	D	Analog Outputs, Bidirectional
—	8, 9	DA, DB	Analog Outputs, Bidirectional
9-12	—	S8-S5	Analog Inputs, Bidirectional
—	10-13	S4B-S1B	Analog Inputs, Bidirectional
13	14	V+	Positive-Supply Voltage Input
14	15	GND	Ground

Functional Diagrams



Monolithic CMOS Analog Multiplexers

DG508A/DG509A

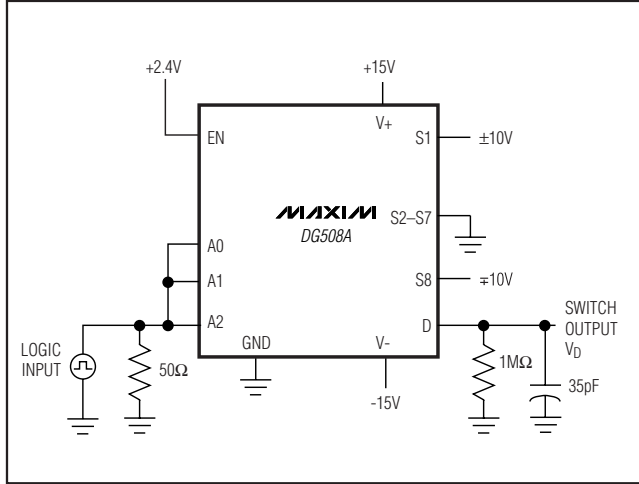


Figure 1a. Switching-Time Test Circuit

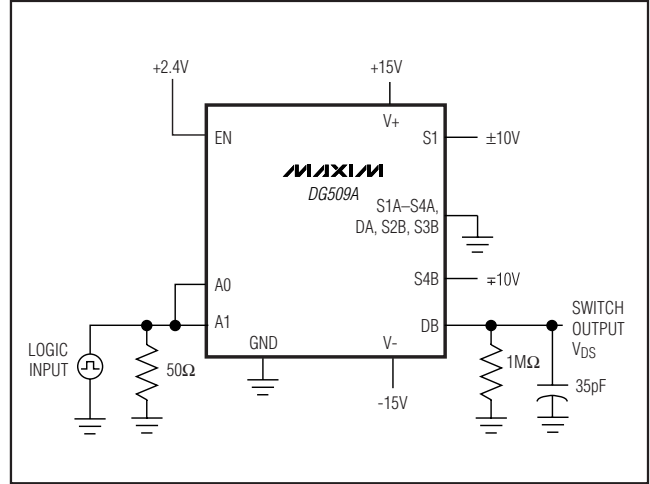


Figure 1b. Switching-Time Test Circuit

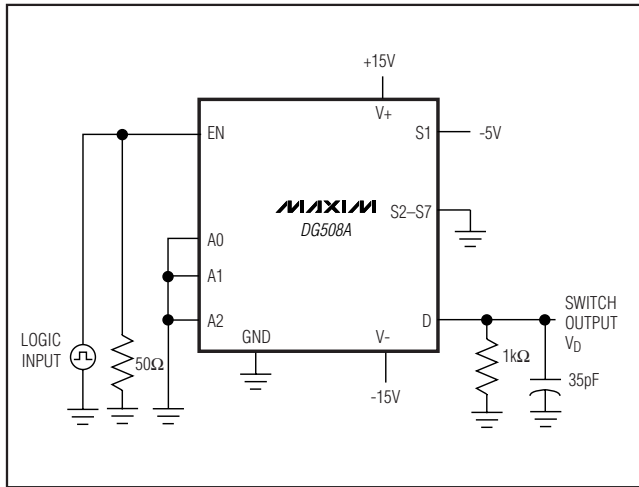


Figure 2a. DG508A Enable-Time Test Circuit

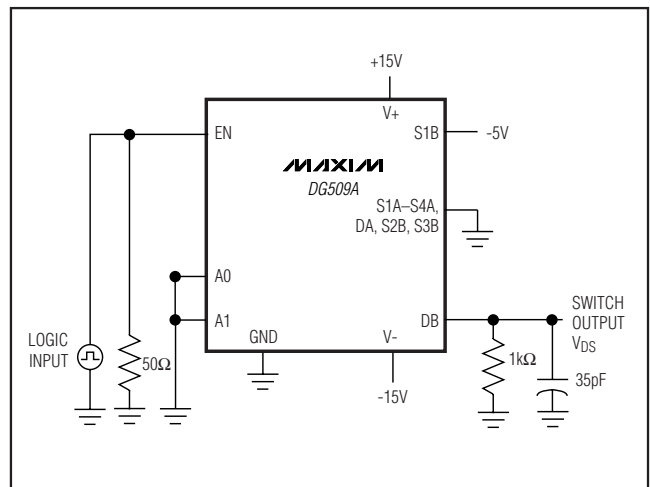


Figure 2b. DG509A Enable-Time Test Circuit

Monolithic CMOS Analog Multiplexers

DG508A/DG509A

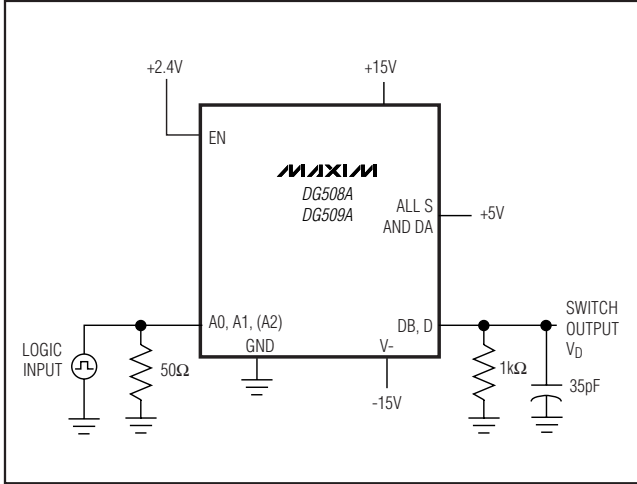


Figure 3. Break-Before-Make Test Circuit

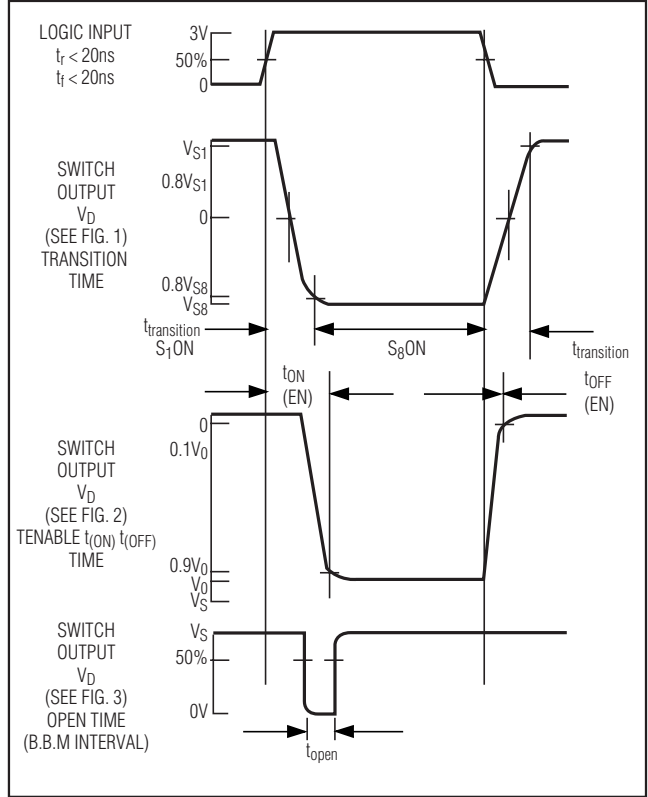


Figure 4. Timing Diagram for Figures 1, 2, and 3

Table 1a. DG508A Truth Table

A2	A1	A0	EN	ON SWITCH
X	X	X	0	NONE
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

X = Don't care.

Table 1b. DG509A Truth Table

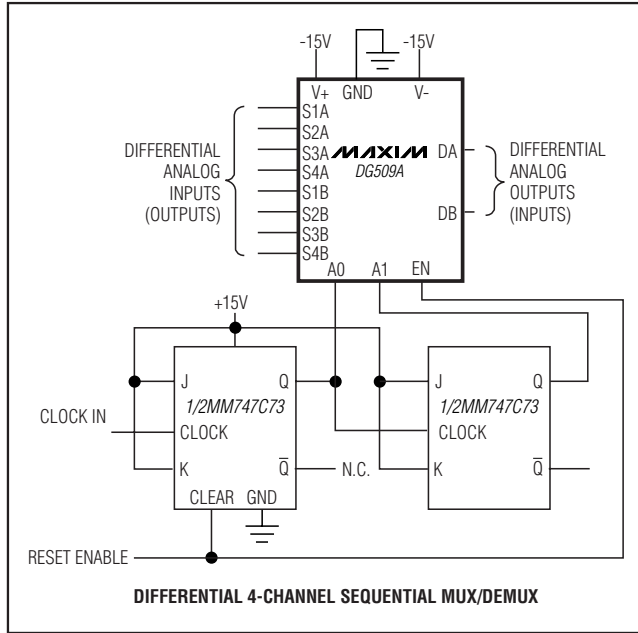
A1	A0	EN	ON SWITCH
X	X	0	NONE
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

X = Don't care.

DG508A/DG509A

Monolithic CMOS Analog Multiplexers

Typical Operating Circuits (continued)



Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
16 Plastic DIP	P16-1	21-0043
16 Wide SO	W16-2	21-0042
16 Narrow SO	S16-5	21-0041
16 CERDIP	J16-3	21-0045

Monolithic CMOS Analog Multiplexers

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
4	5/10	Updated the "Drain-Source On-Resistance" parameter for both the $T_A = +25^\circ\text{C}$ and $T_A = T_{\text{MIN}}$ to T_{MAX} conditions.	2, 4
		Deleted the QFN package from the <i>Ordering Information</i> , <i>Absolute Maximum Ratings</i> , <i>Pin Configurations</i> , <i>Pin Descriptions</i> , and <i>Package Information</i> sections.	1, 2, 5, 8
		Added the DG508AMY/PR and DG509AMY/PR parts to the <i>Ordering Information</i> table.	1

DG508A/DG509A

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